

/ Descriptions

N-Channel Enhancement Mode Field Effect Transistor in a PDFN 3 3A-8L Plastic Package.

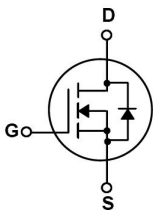
/ Features

$V_{DS} (V) = 40V$ $I_D = 57A (V_{GS} = \pm 20V)$
 $R_{DS(ON)}@10V \ 5mR(Typ.4.5mR)$
 $R_{DS(ON)}@4.5V \ 10mR(Typ.6.2mR)$
HF Product.

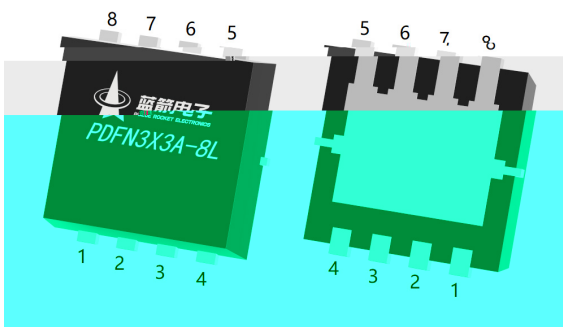
/ Applications

Load Switch Applications,Battery Power Management.

/ Equivalent Circuit



/ Pinning



出脚	定义
Pin1	S
Pin2	S
Pin3	S
Pin4	G
Pin5	D
Pin6	D
Pin7	D
Pin8	D

/ Marking

See Marking Instructions.

BRCS050N04YB

Rev.A Jul.-2023



DATA SHEET

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	40	V
Drain Current	I_D		

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\text{ A}$	40	43		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V$ $V_{GS}=0V$			1	A
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 0.1	A
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\text{ A}$	1.0	1.7	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=20A$		4.5	5	m
		$V_{GS}=4.5V$ $I_D=10A$		6.2	10	m
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=1A$			1.2	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		2900		pF
Output Capacitance	C_{oss}			210		
Reverse Transfer Capacitance	C_{rss}			200		
Gate resistance	R_g	$V_{GS}=0V$ $V_{DS}=0V$ $f=1MHz$		2.5		
Total Gate Charge	$Q_{g(10V)}$	$V_{GS}=10V$ $V_{DS}=20V$ $I_D=20A$		70		nC
Total Gate Charge	$Q_{g(4.5V)}$			15		
Gate Source Charge	Q_{gs}			15		
Gate Drain Charge	Q_{gd}			22		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1$ $R_{GEN}=3.0$		15		ns
Turn-On Rise Time	t_r			30		
Turn-Off Delay Time	$t_{d(off)}$			54		
Turn-Off Fall Time	t_f			20		

/ Electrical Characteristic Curve

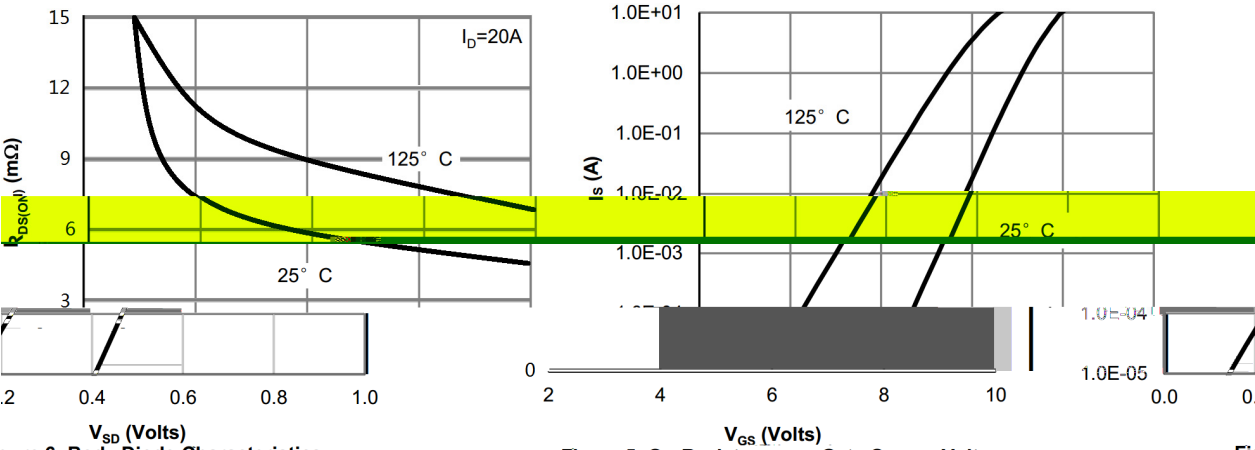
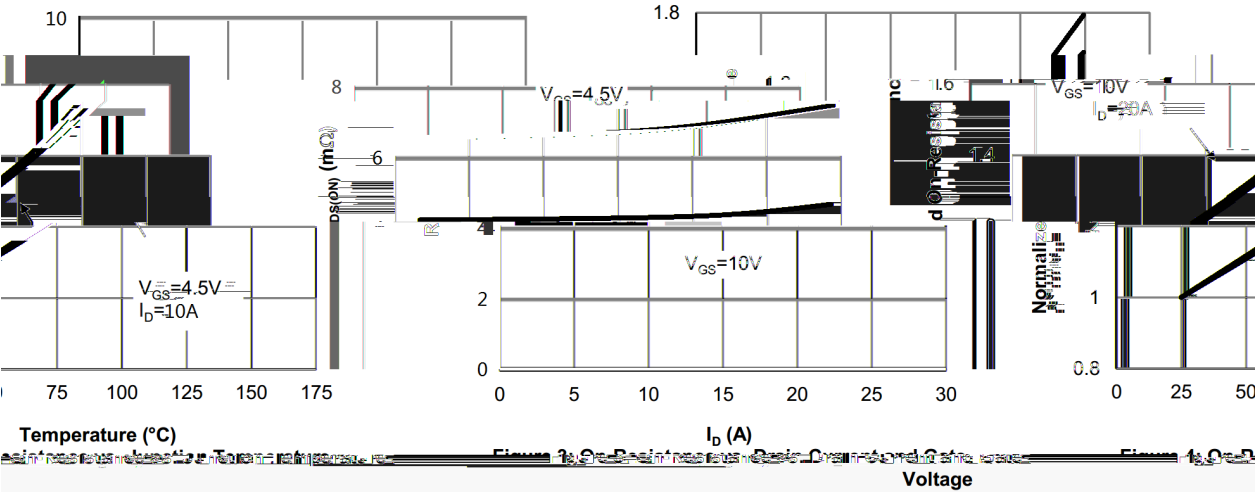
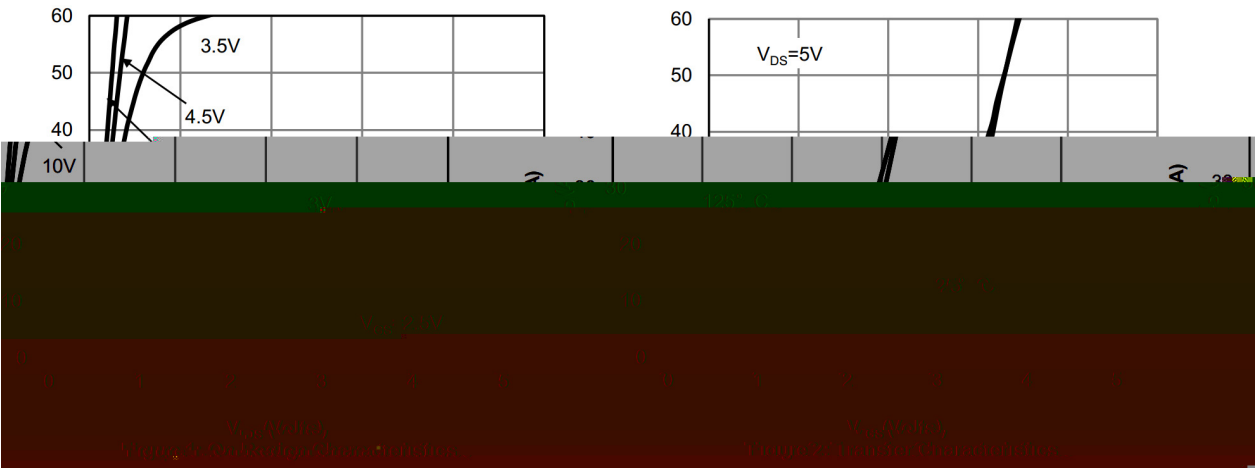


Figure 6: Body-Diode Characteristics

Figure 5: On-Resistance vs. Gate-Source Voltage

Fig

I Electrical Characteristic Curve

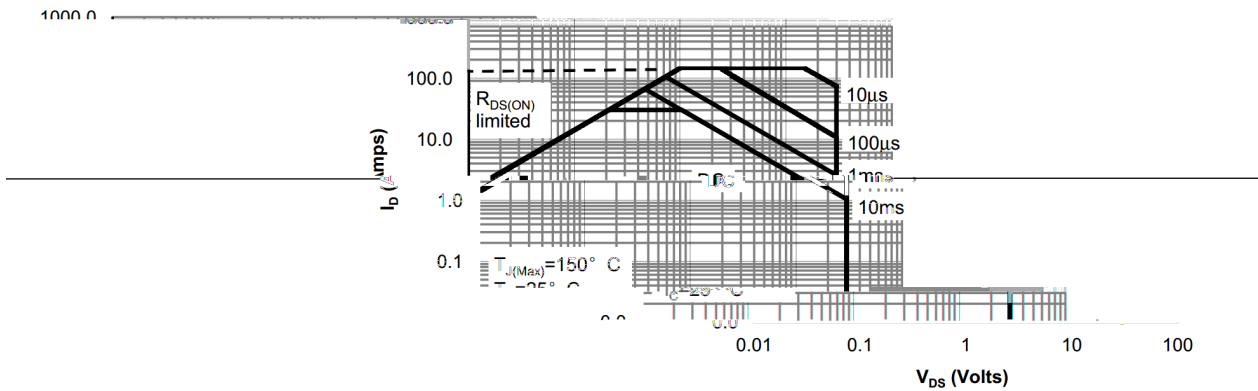
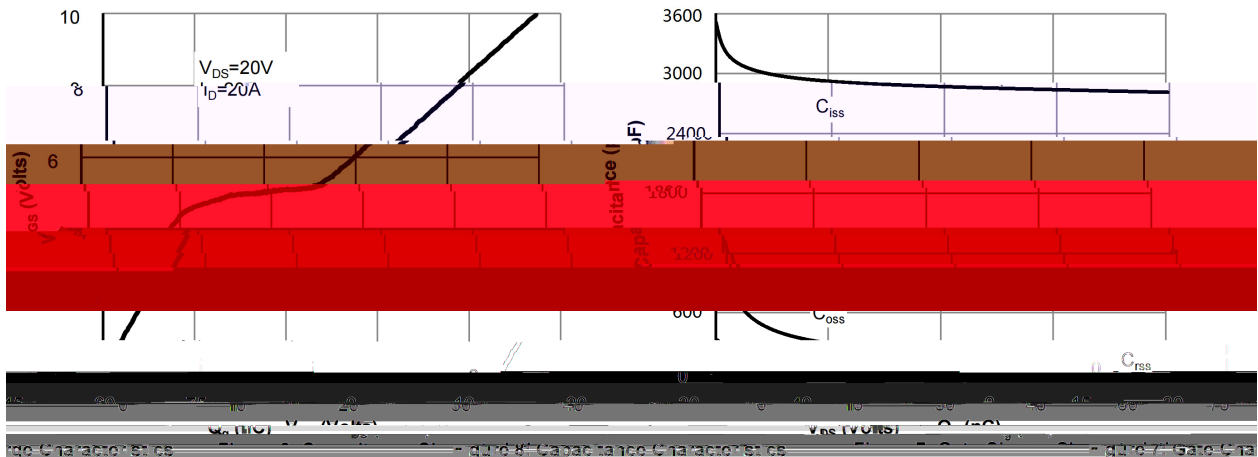


Figure 9: Maximum Allowable Power Dissipation vs. Pulse Width

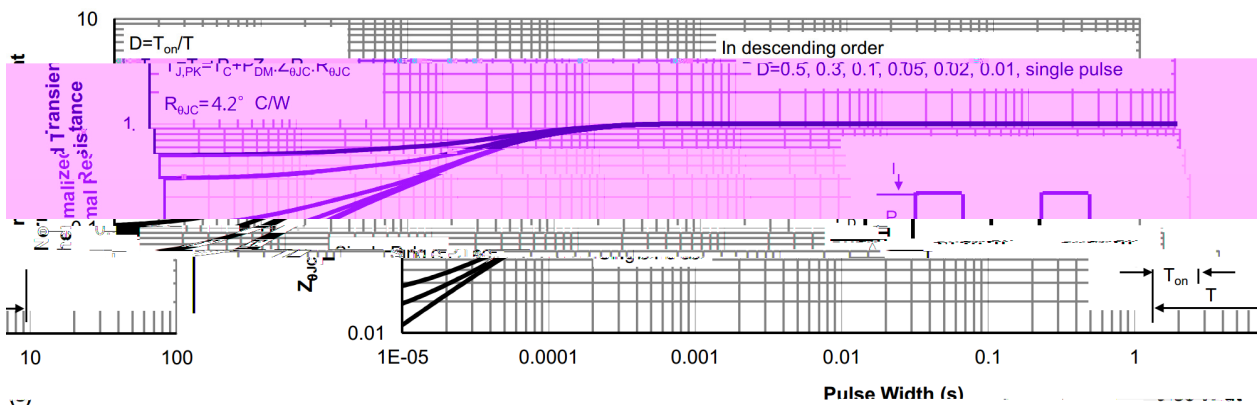
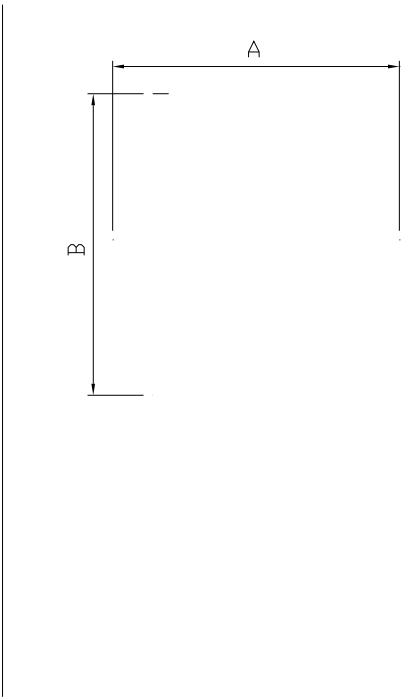


Figure 10: Normalized Maximum Transient Thermal Impedance vs. Pulse Width

/ Package Dimensions

PDFN3X3A-8L

Unit:mm



Dimensions In Millimeterer			
Symbol	MIN	TYP	MAX
A	3.20	3.30	3.40
A1	3.10	3.15	3.20
B	3.20	3.30	3.40
B1	2.95	3.00	3.05

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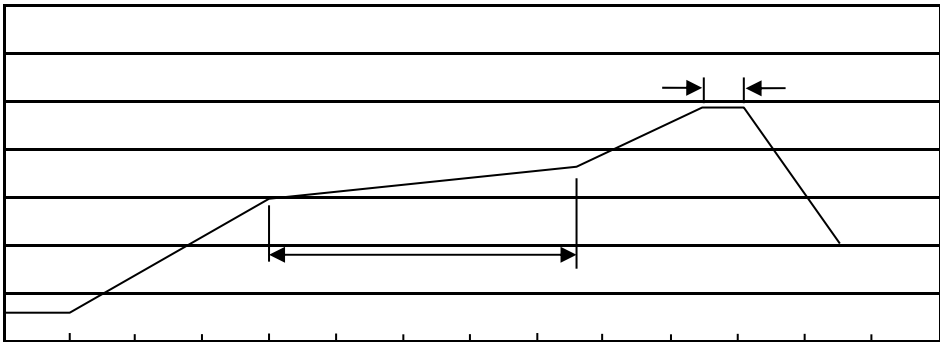
BRCS050N04YB

Rev.A Jul.-2023



DATA SHEET

() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

150 180

60 90sec;

1.Preheating:150~180 , Time:60~90sec.
- 2

245 5

5 0.5sec;

2.Peak Temp.:245 5 , Duration:5 0.5sec.
- 3

2 10

/sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260 5

10 1 sec.

Temp.:260 5

Time:10 1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box	Outer Box
PDFN 3×3A-8L	5,000	2	10,000	6	60,000	13 ×12	360×360×50	380×335×366

/ Notices